NSN 5962-01-135-2106

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Во	dy Length:
1.3	10 inches
Во	dy Width:
0.6	00 inches
Во	dy Height:
0.0	152 inches
Ма	ximum Power Dissipation Rating:
400	0.0 milliwatts
Ор	erating Tempurature Range:
+0.	.0/+75.0 degrees celsius
Sto	prage Tempurature Range:
-65	5.0/+150.0 degrees celsius
En	d Application:
Tra	aining dev 08783
Fe	atures Provided:
He	rmetically sealed and programmable and expandable and wire-or outputs and w/enable
Inc	losure Material:
Ce	ramic and glass
Inc	closure Configuration:
Du	al-in-line
Ou	tput Logic Form:
Tra	ansistor-transistor logic
Inp	out Circuit Pattern:
8 ir	nput
Те	rminal Surface Treatment:
So	lder
Vo	Itage Rating And Type Per Characteristic:
-1.	5 volts power source and 5.5 volts power source
Tin	ne Rating Per Chacteristic:
75.	00 nanoseconds propagation delay time, low to high level output
Ме	emory Device Type:
Ro	m
Me	emory Capacity:
Un	known
Те	rminal Type And Quantity:
24	printed circuit
Sh	elf Life:
N/a	a
Un	it Of Measure:
 De	militarization:
	s - demil/mli

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